



# **SNS COLLEGE OF TECHNOLOGY**

Kurumbapalayam (Po), Coimbatore – 641 107

**An Autonomous Institution**

Accredited by NBA – AICTE and Accredited by NAAC – UGC with 'A' Grade  
Approved by AICTE, New Delhi & Affiliated to Anna University, Chennai



**DEPARTMENT OF ELECTRONICS AND COMMUNICATION ENGINEERING**

**COURSE NAME : 19EC201-ANALOG ELECTRONIC CIRCUITS**

**II YEAR /III SEMESTER**

**Unit 2- BJT AND FET AMPLIFIERS**

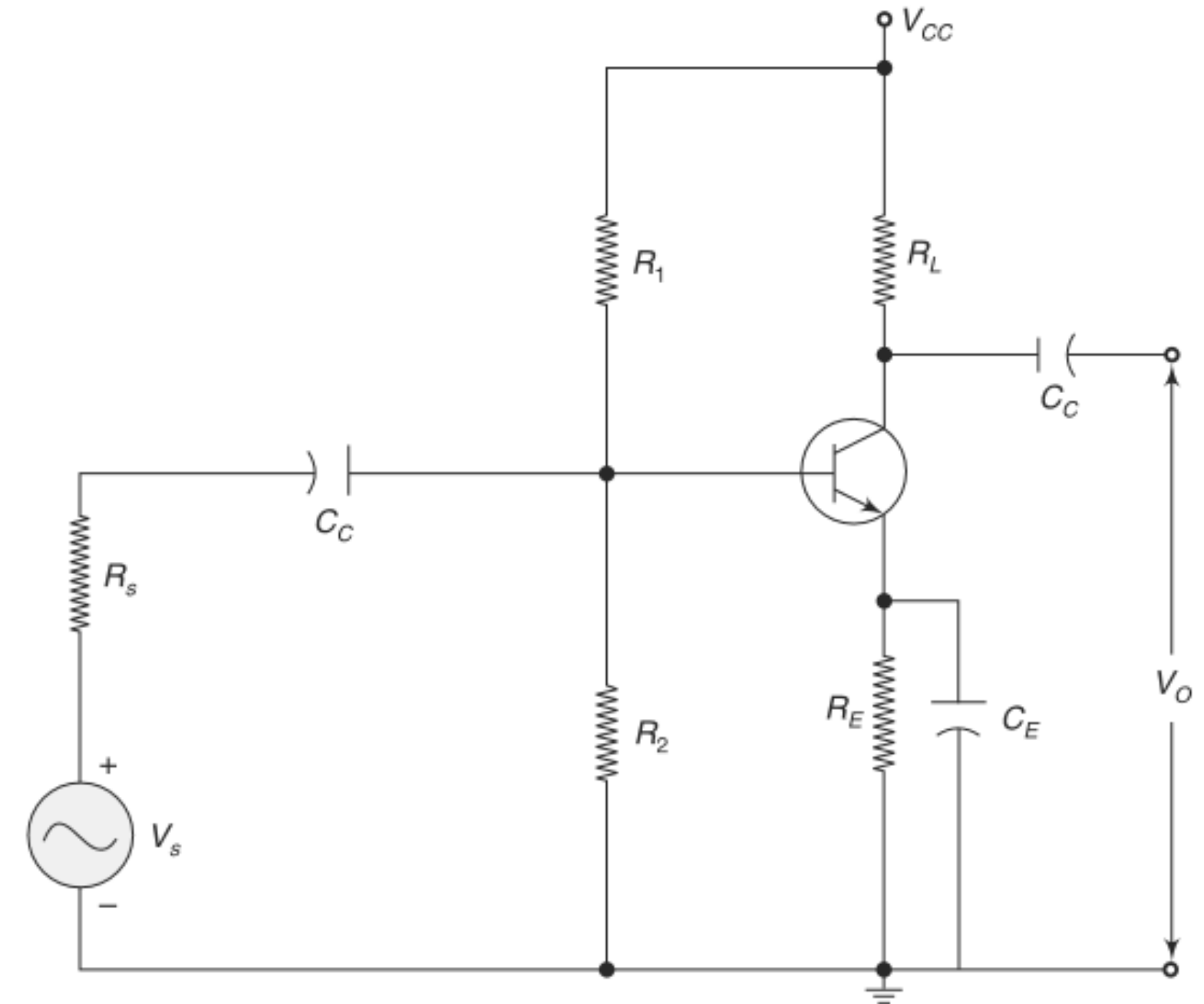
**Topic 4 : Low frequency analysis of common emitter amplifier**



# Low Frequency Analysis of CE Amplifier

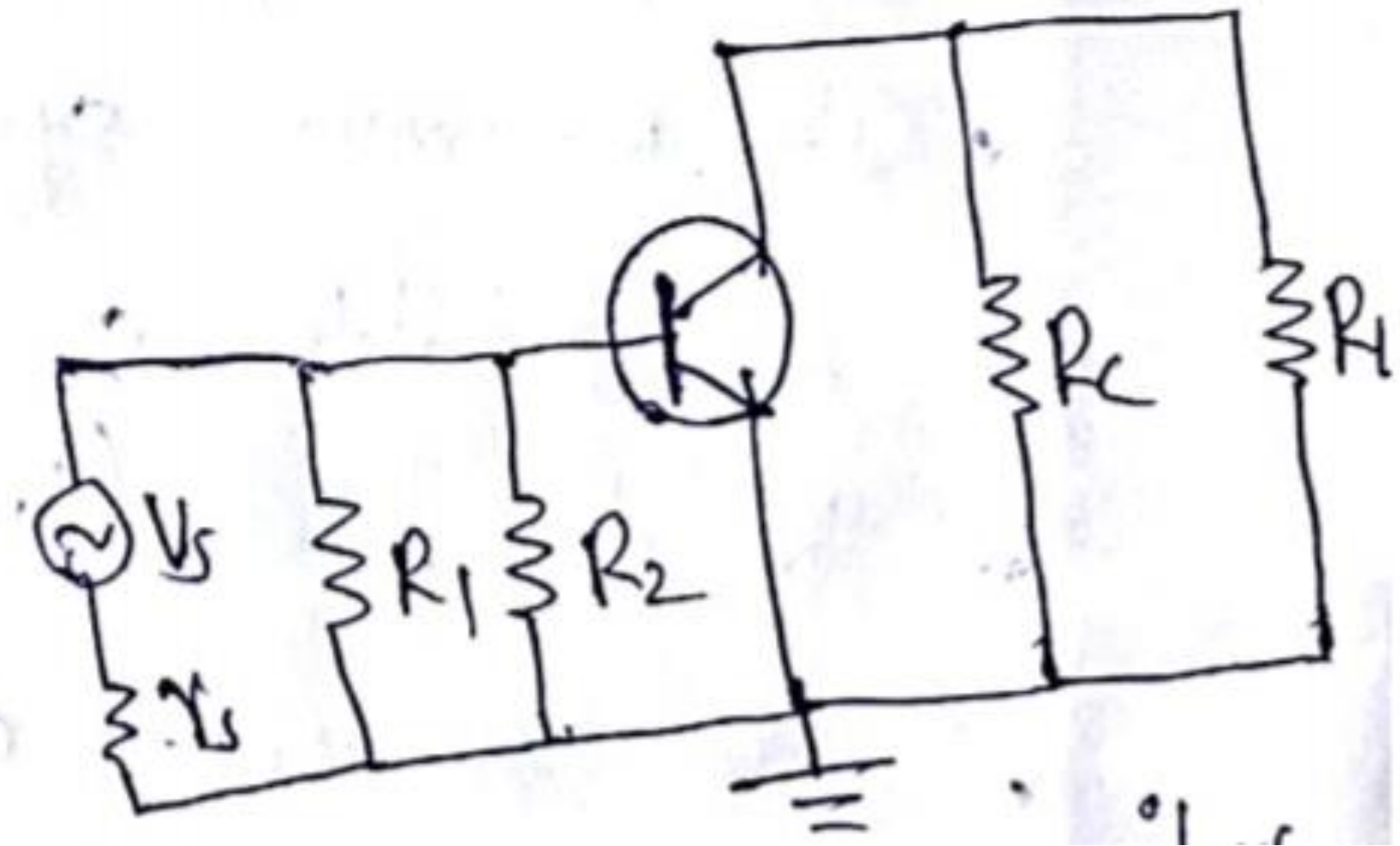
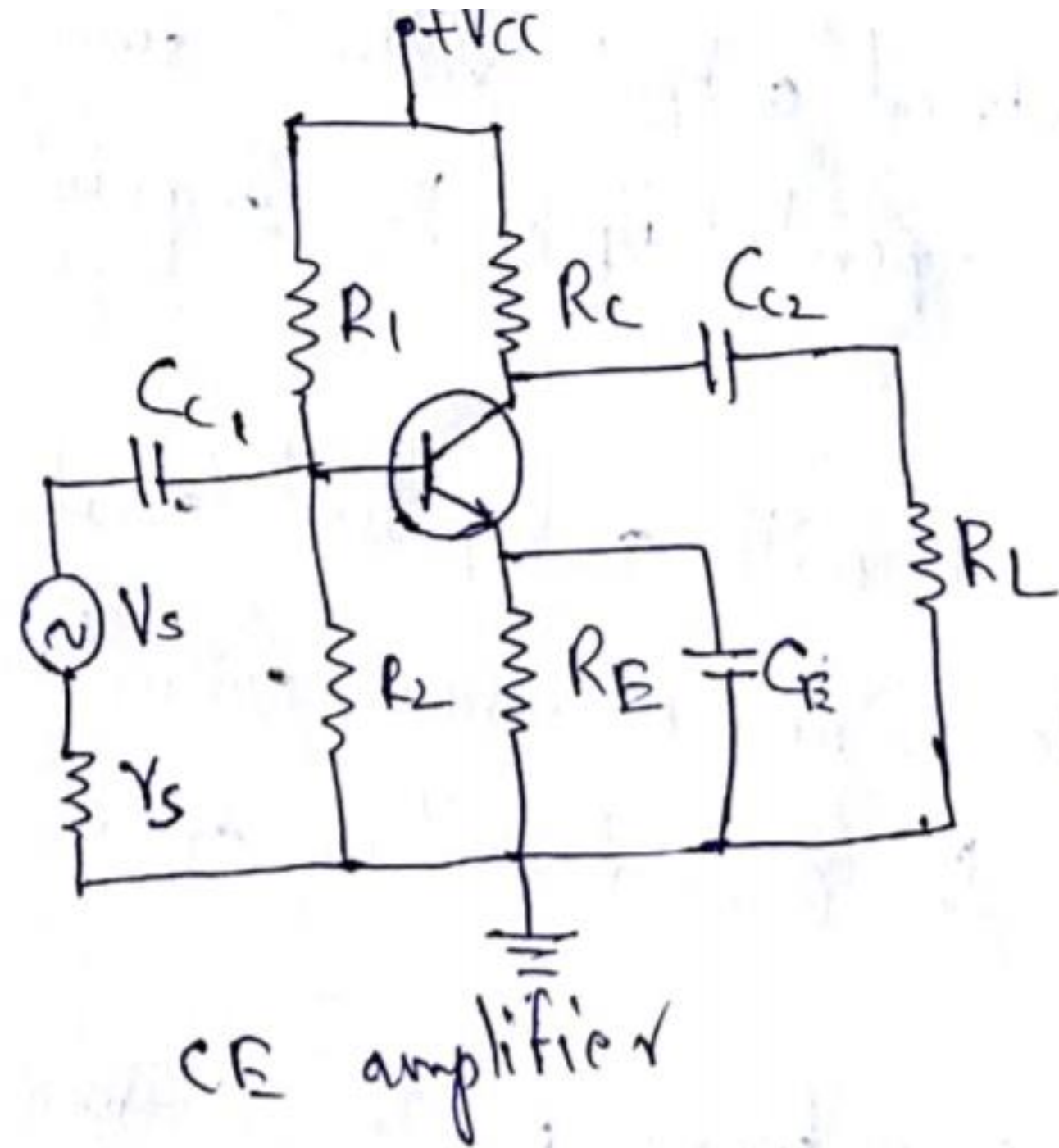


- 180 degree phase shift
- High voltage gain



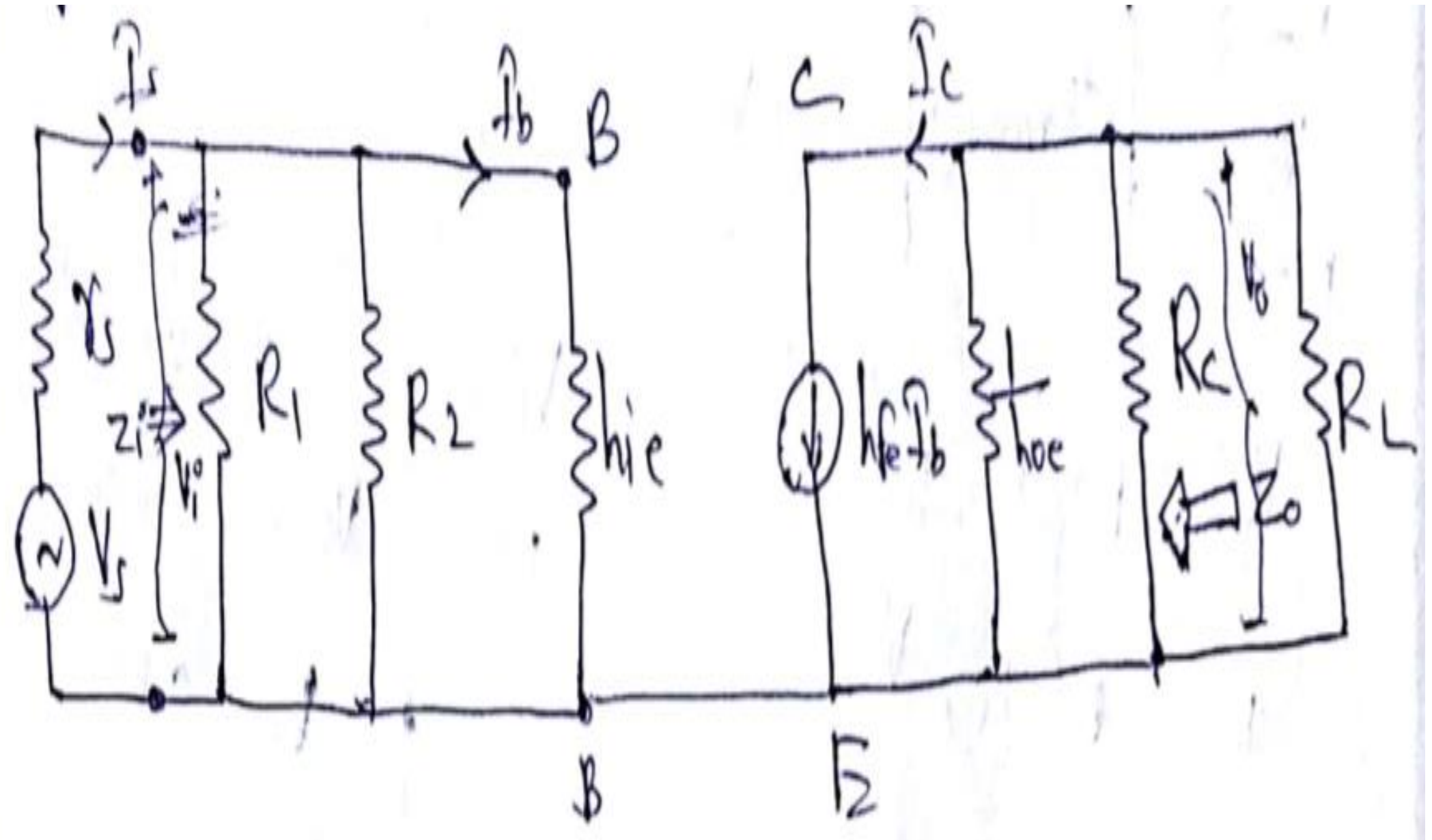
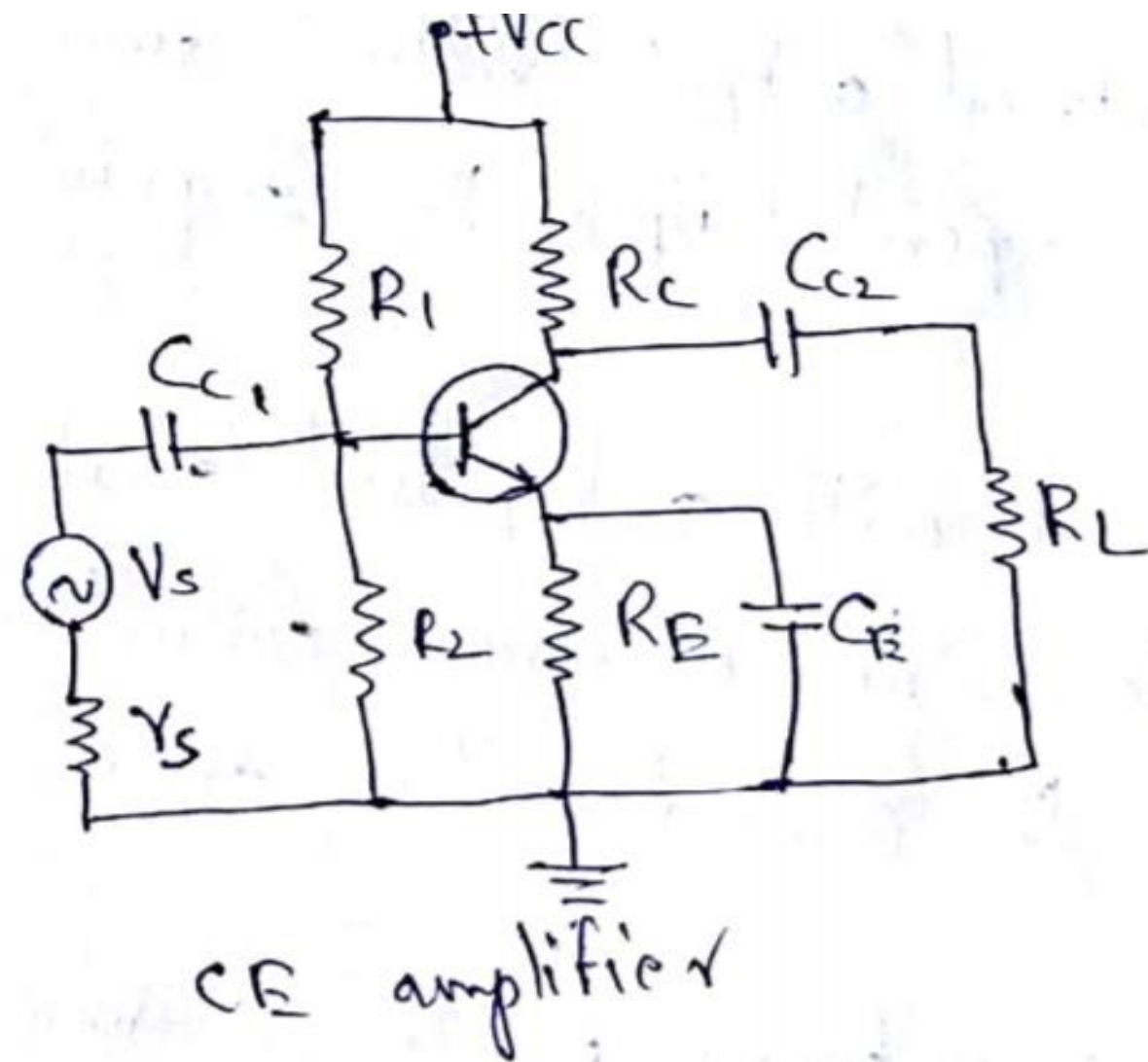


# Small signal Analysis of CE Amplifier





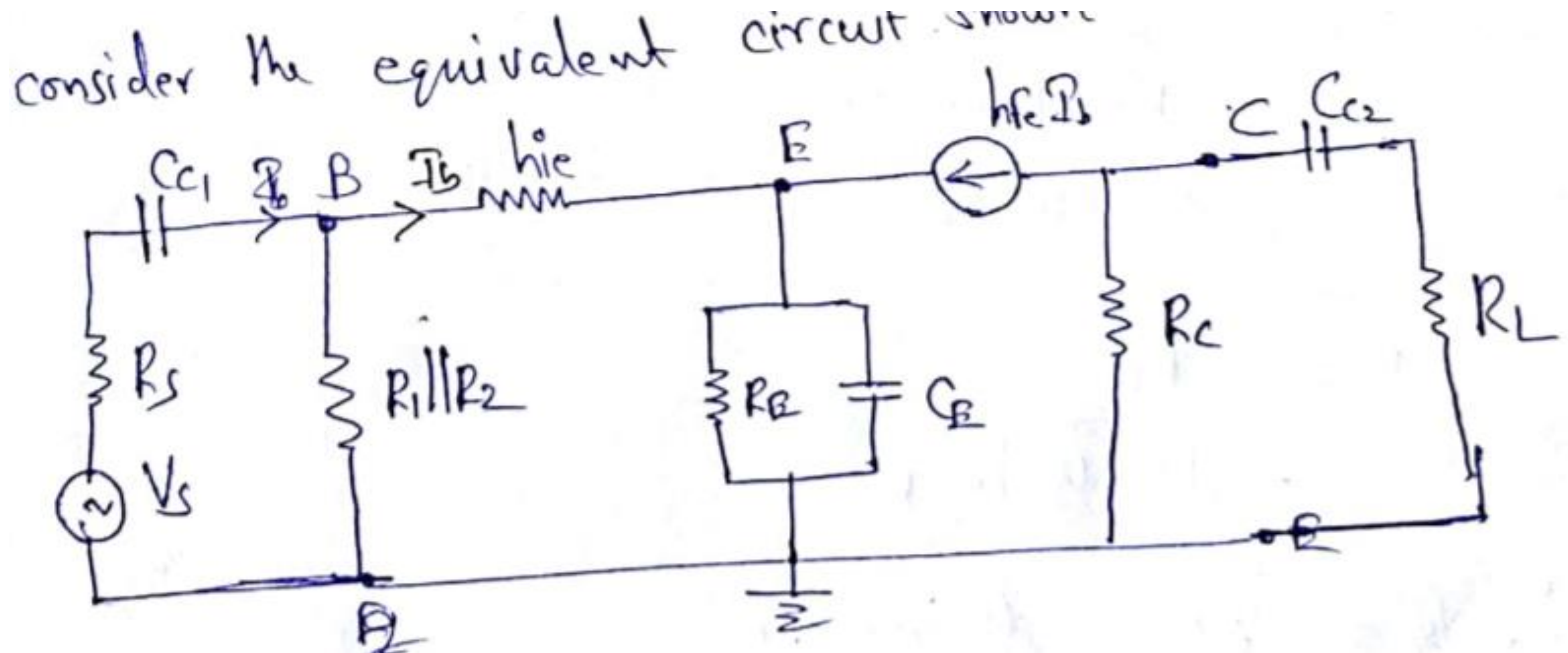
# Small signal Analysis of CE Amplifier





# Equivalent Circuit

- At low frequency, the effects of coupling and bypass capacitors are to be considered.

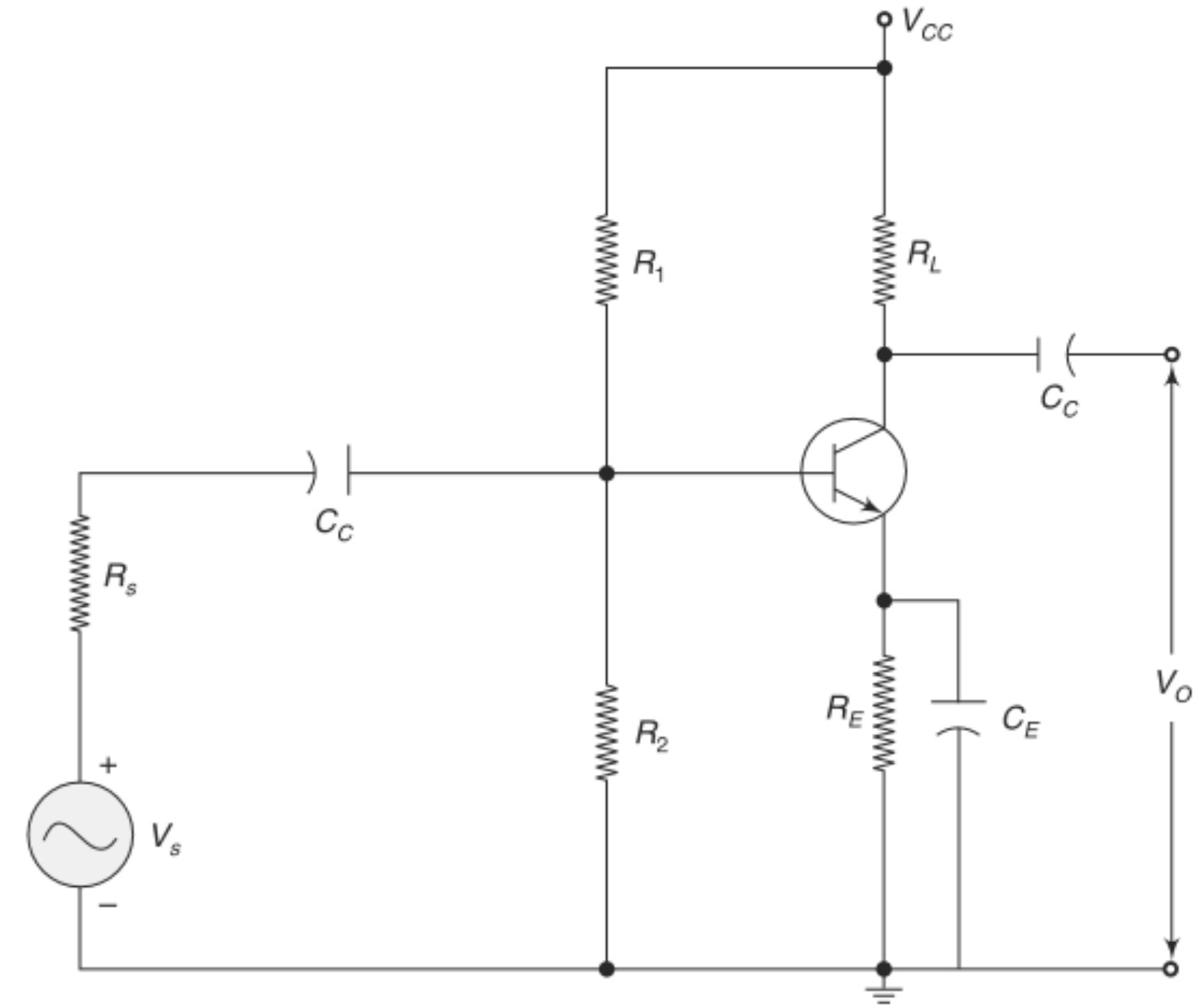




# Analysis



Draw the Input and output waveforms





# Low Frequency Analysis

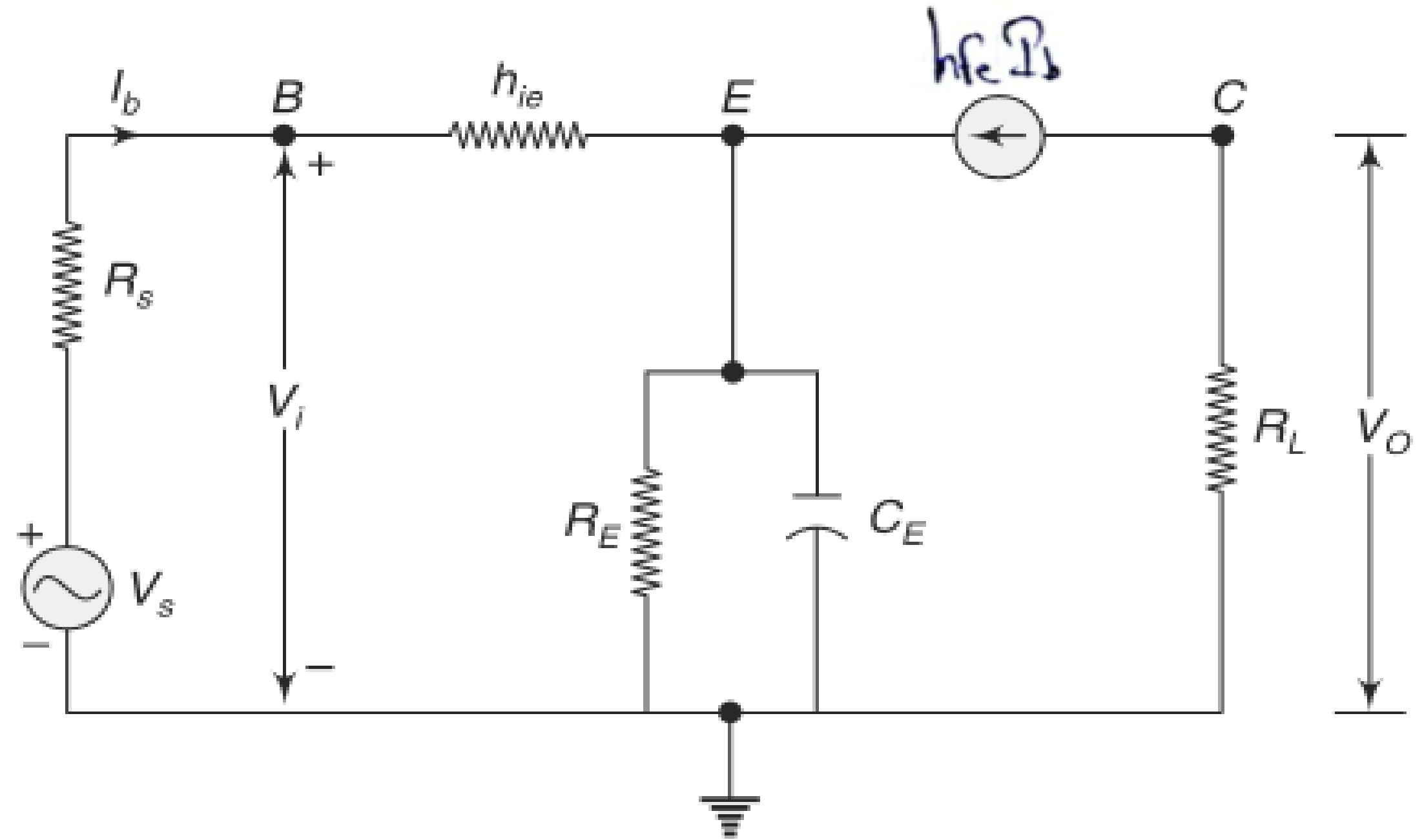


- Voltage gain at low frequency

- $A_V = V_0 / V_s$

$$V_0 = -h_{fe} I_b R_L$$

$$I_b = \frac{V_s}{R_s + R_i}$$





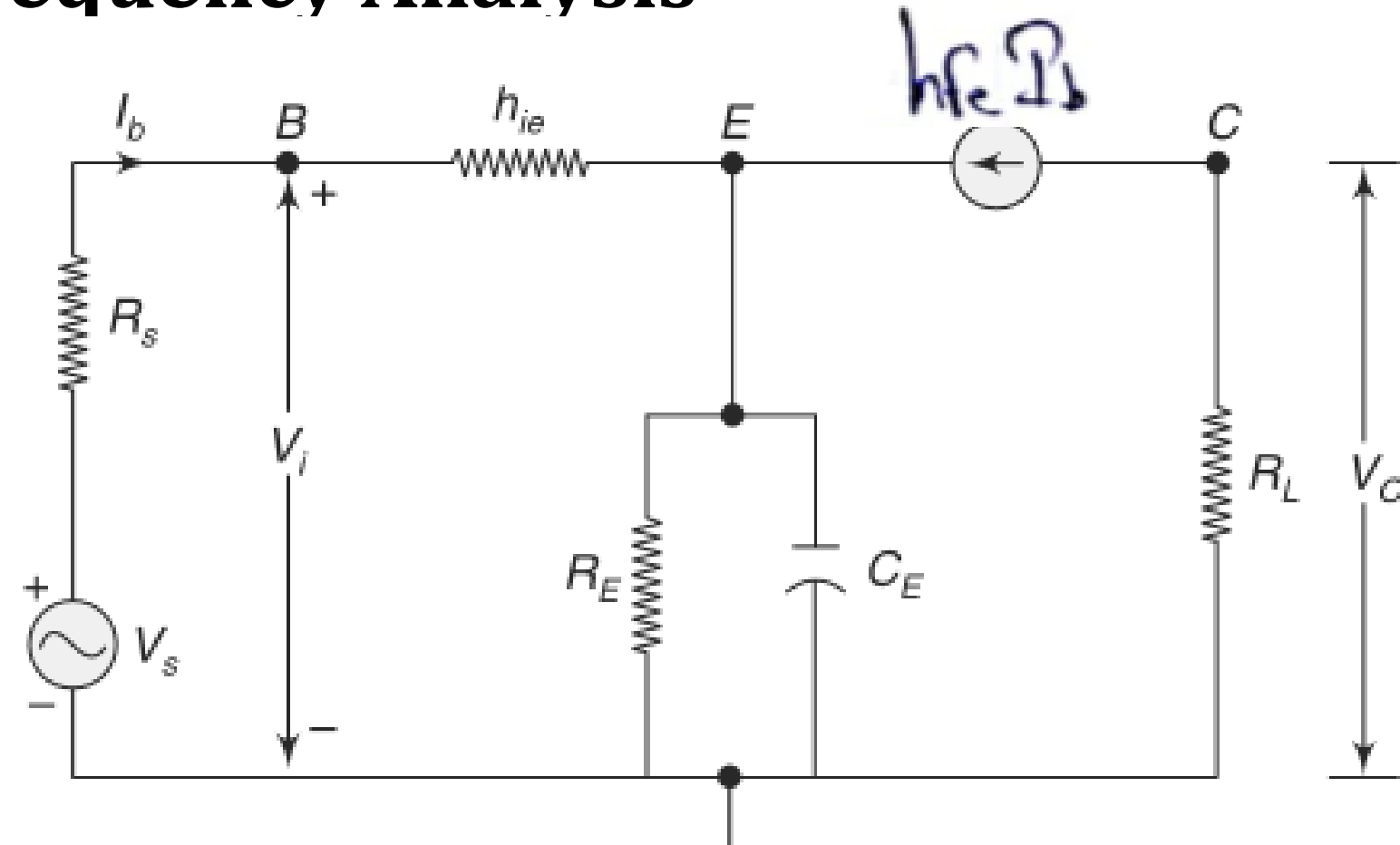
# Low Frequency Analysis



$$R_i = h_{ie} + (1 + h_{fe}) Z_E$$

$$Z_E = R_E \parallel X_{CE}$$

$$= \frac{R_E}{1 + j\omega C_E R_E}$$



$$Z_E = \frac{R_E X_{CE}}{R_E + X_{CE}} = \frac{R_E \times \frac{1}{j\omega C_E}}{R_E + \frac{1}{j\omega C_E}}$$

$$Z_E = \frac{R_E}{\frac{j\omega C_E R_E + 1}{j\omega C_E}}$$



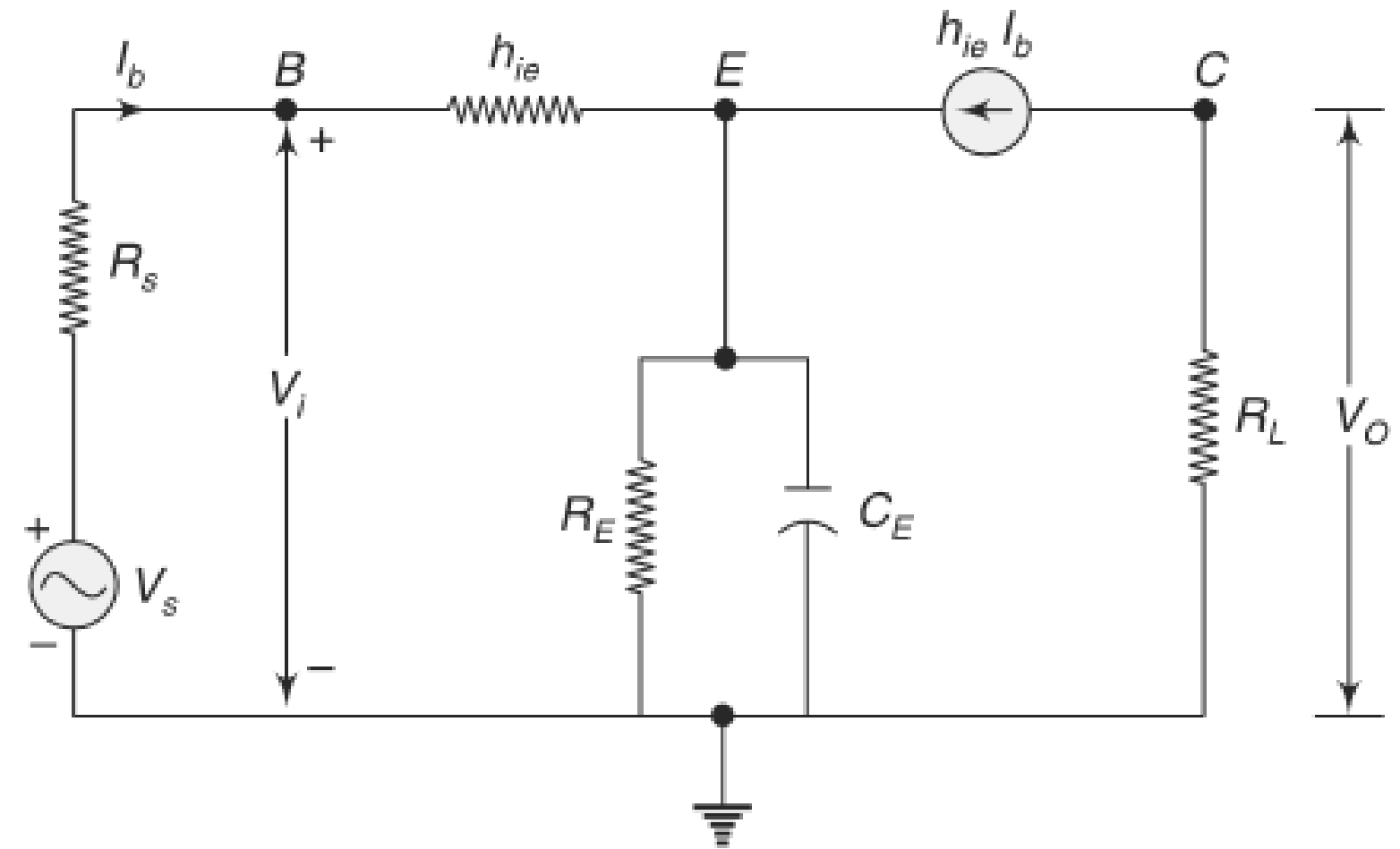


# Low Frequency Analysis



$$R_i = h_{ie} + \frac{(1 + h_{fe}) R_E}{1 + j\omega C_E R_E}$$

$$I_b = \frac{V_s}{R_s + h_{ie} + \frac{(1 + h_{fe}) R_E}{1 + j\omega C_E R_E}}$$

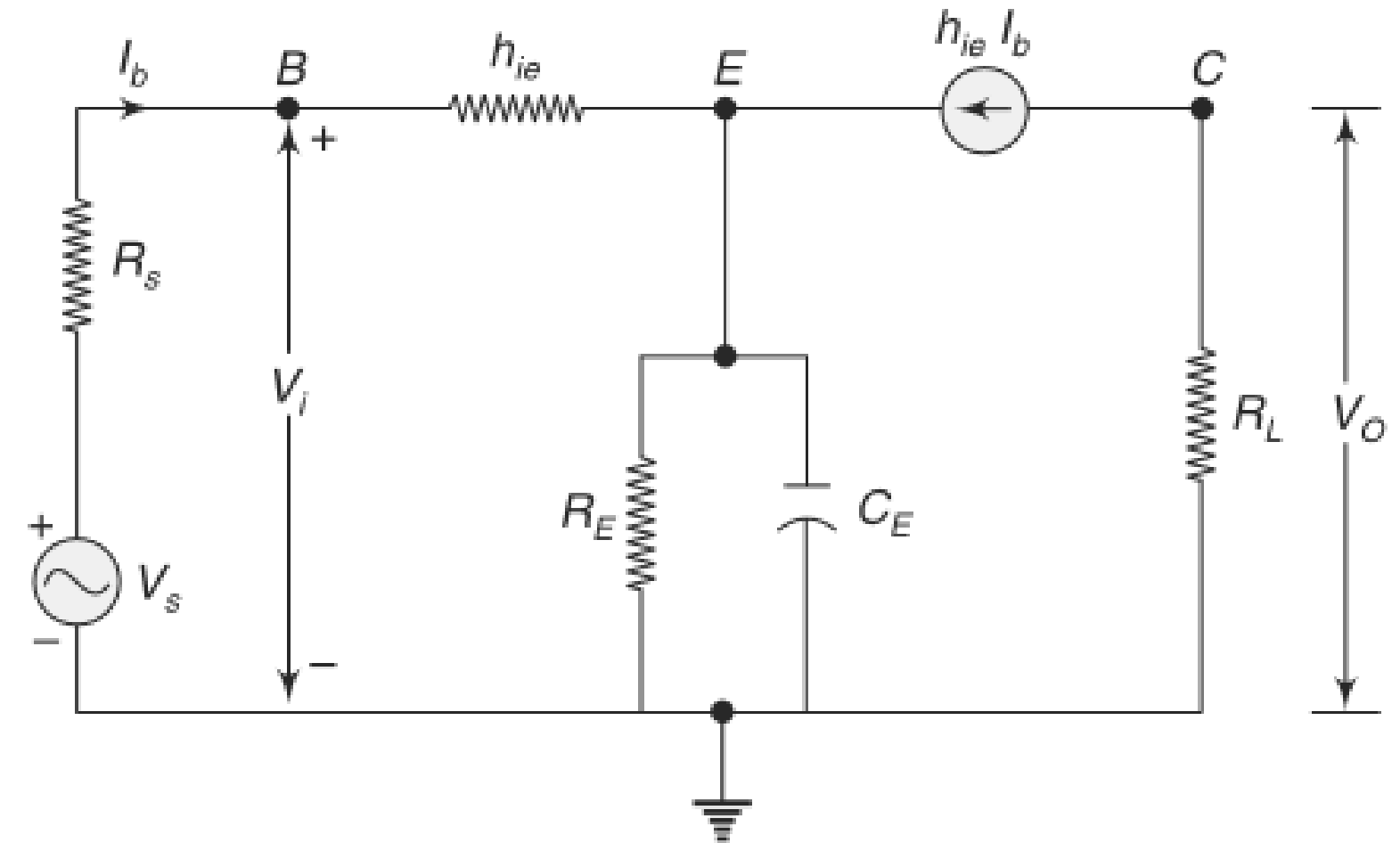




# Voltage Gain at Low Frequency

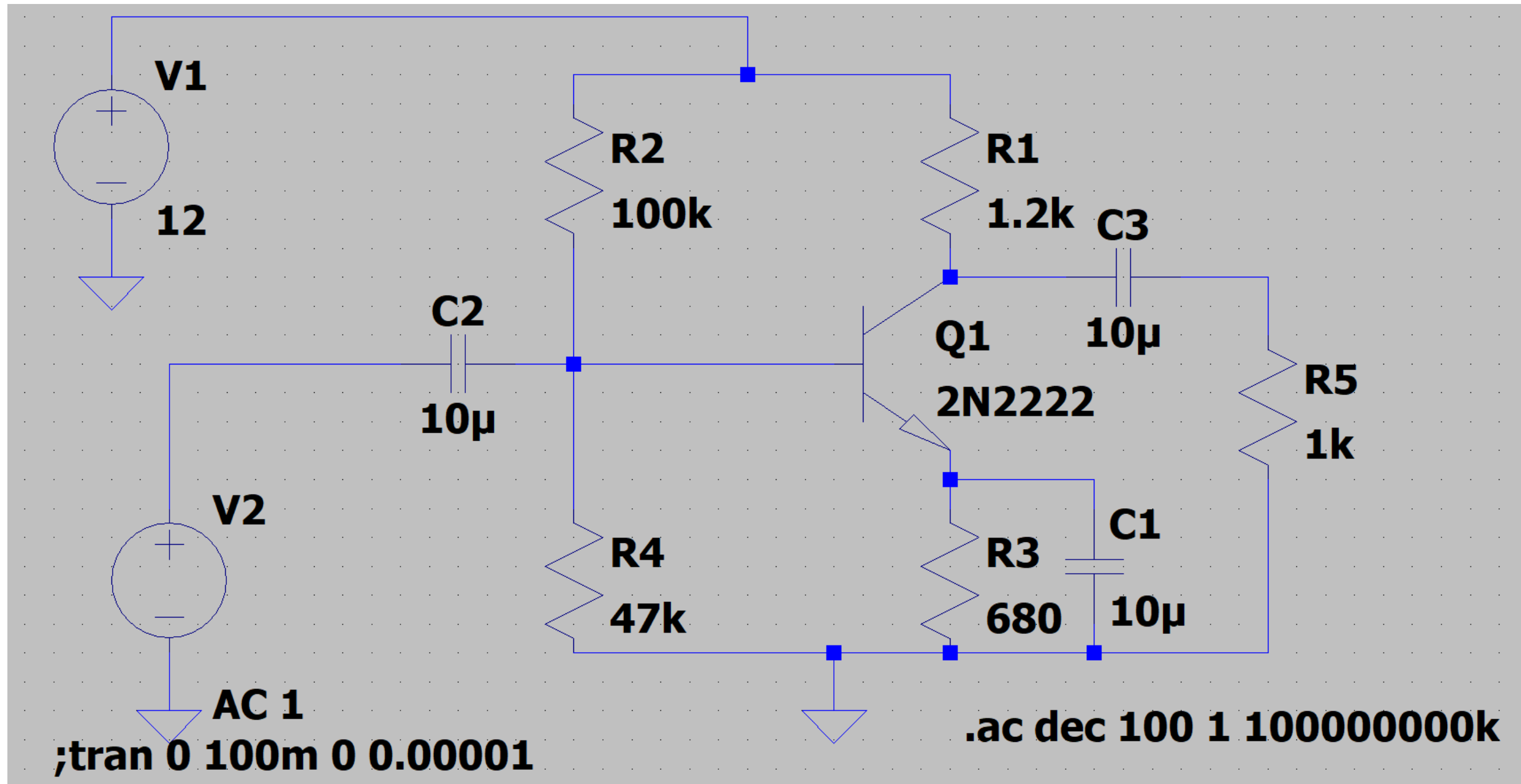


$$V_O = -h_{fe}R_L \frac{V_s}{R_s + h_{ie} + \frac{(1 + h_{fe}) R_E}{1 + j\omega C_E R_E}}$$
$$A_{V(LF)} = \frac{V_O}{V_s} = \frac{-h_{fe}R_L}{R_s + h_{ie} + \frac{(1 + h_{fe}) R_E}{1 + j\omega C_E R_E}}$$



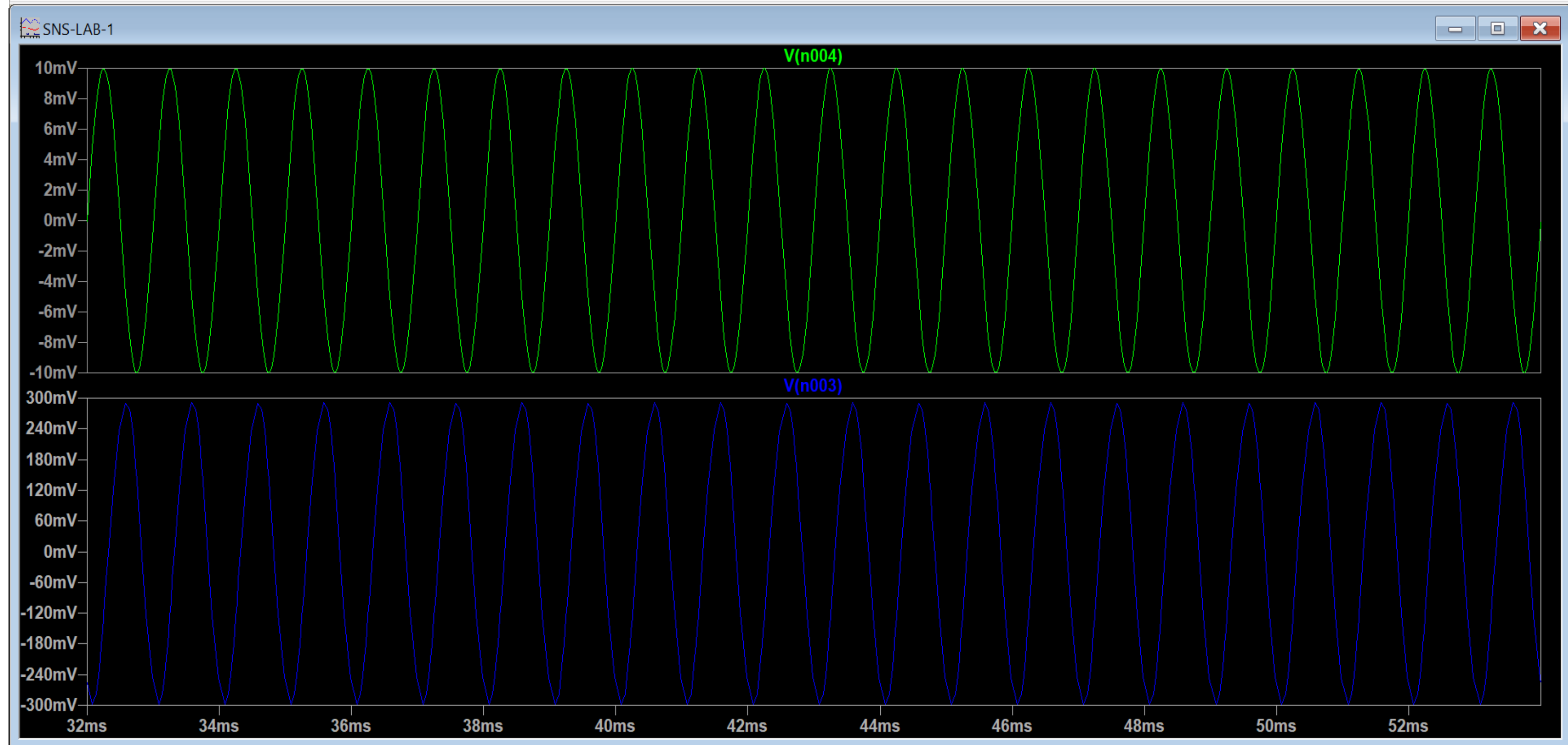


# LTSPICE-CE AMPLIFIER



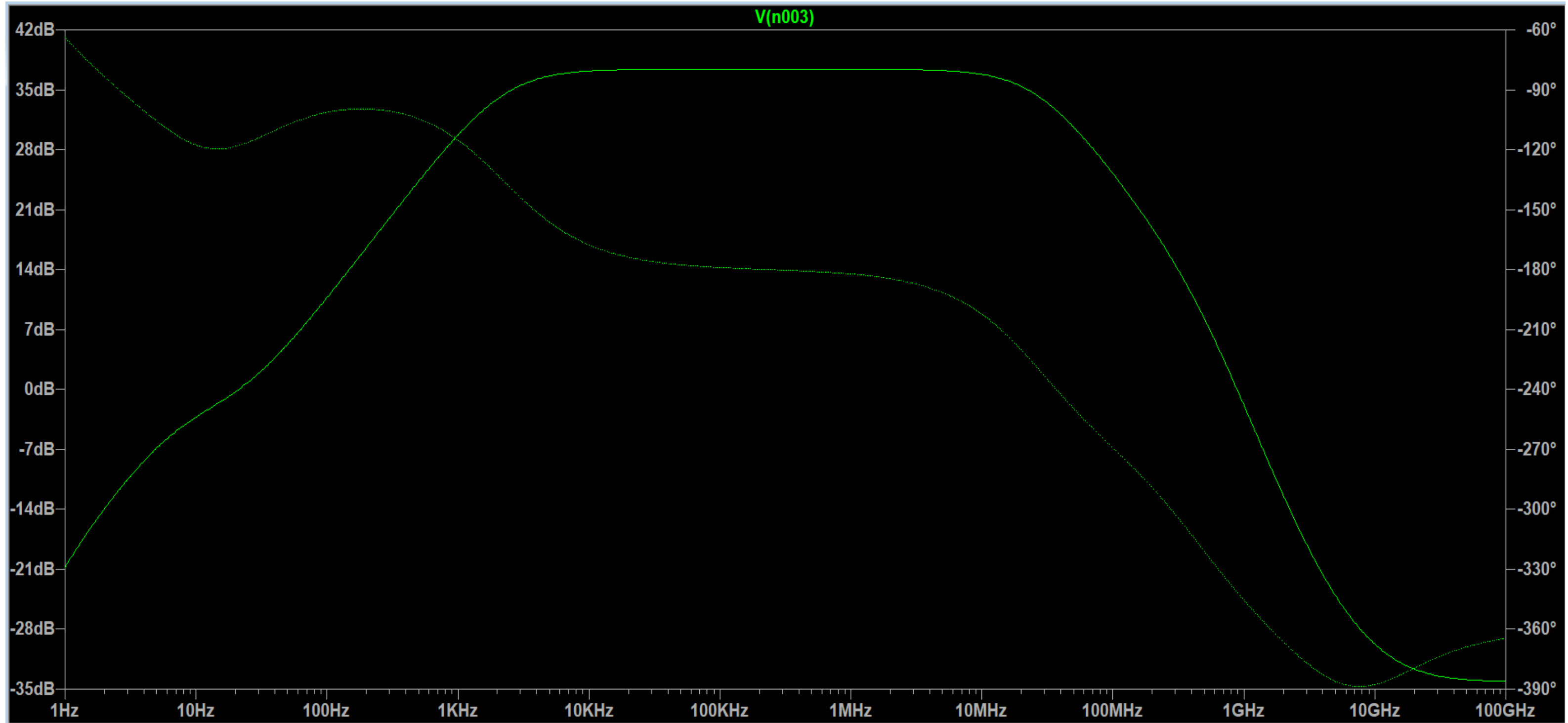


# Input and Output Waveforms





# Frequency Response

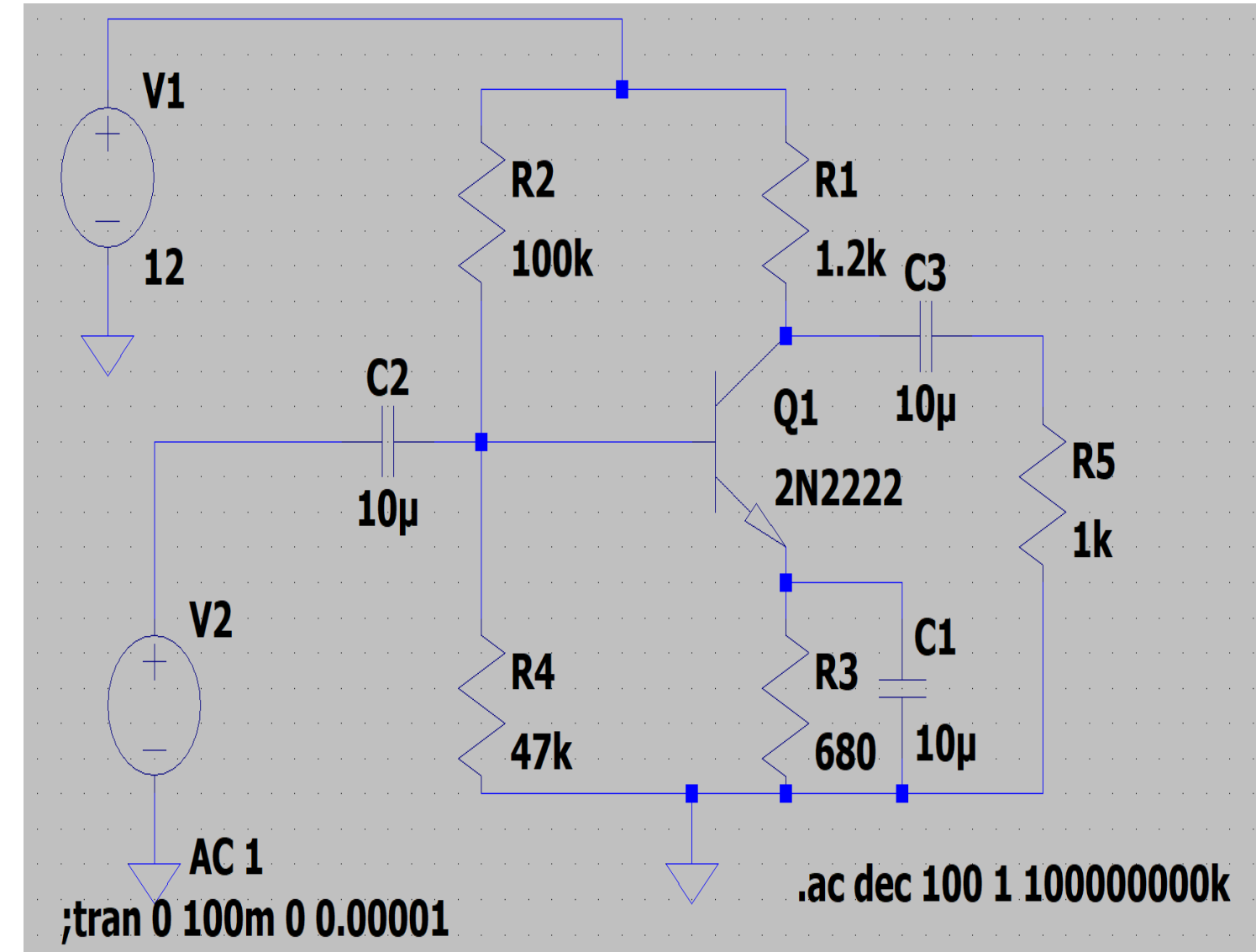




# Advantages & Disadvantages

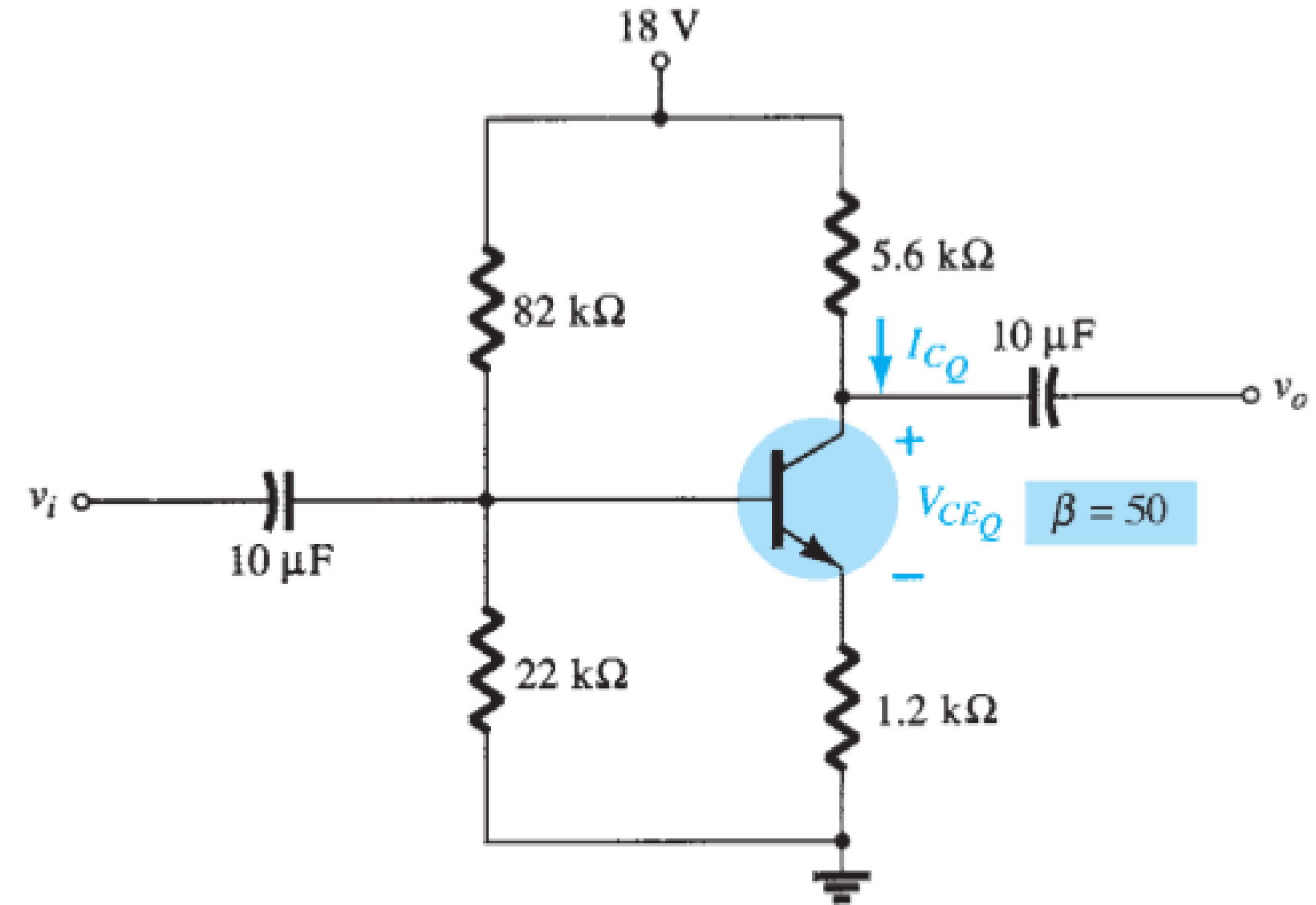


- High Voltage gain
- High bandwidth
- Complex circuit design-Disadvantage





# Assessment-1





# Assessment 1 (Answer)



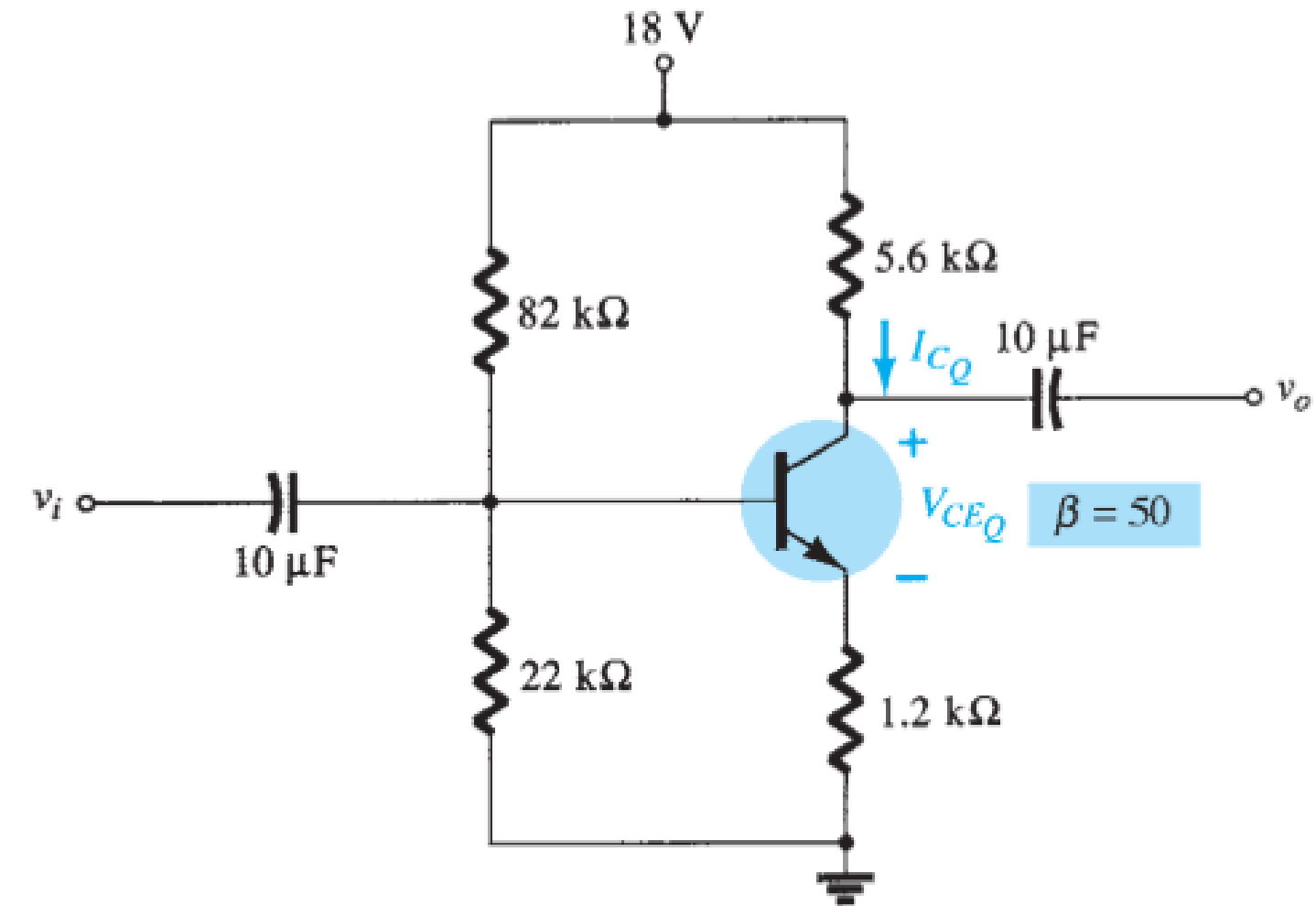
$$R_{Th} = R_1 \parallel R_2 = 82 \text{ k}\Omega \parallel 22 \text{ k}\Omega = 17.35 \text{ k}\Omega$$

$$E_{Th} = \frac{R_2 V_{CC}}{R_1 + R_2} = \frac{22 \text{ k}\Omega (18 \text{ V})}{82 \text{ k}\Omega + 22 \text{ k}\Omega} = 3.81 \text{ V}$$

$$I_B = \frac{E_{Th} - V_{BE}}{R_{Th} + (\beta + 1)R_E} = \frac{3.81 \text{ V} - 0.7 \text{ V}}{17.35 \text{ k}\Omega + (51)(1.2 \text{ k}\Omega)} = \frac{3.11 \text{ V}}{78.55 \text{ k}\Omega} = 39.6 \mu\text{A}$$

$$I_{CQ} = \beta I_B = (50)(39.6 \mu\text{A}) = 1.98 \text{ mA}$$

$$\begin{aligned} V_{CEQ} &= V_{CC} - I_C(R_C + R_E) \\ &= 18 \text{ V} - (1.98 \text{ mA})(5.6 \text{ k}\Omega + 1.2 \text{ k}\Omega) \\ &= 4.54 \text{ V} \end{aligned}$$







# References



Electronic Devices and Circuits By Salivahanan

**Thank You**